

PATENT  
1163-0479P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: MURAKAMI, Hideaki                      Conf.:  
Appl. No.: NEW    Group:  
Filed: November 3, 2003                      Examiner:  
For: SEMICONDUCTOR STRUCTURE WITH PARTIALLY  
ETCHED GATE AND METHOD OF FABRICATING THE  
SAME

PRELIMINARY AMENDMENT

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

November 3, 2003

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

This amendment includes:

Amendments to the Specification

Remarks